

# **Topic 22**

## **22 Different kinds of LDs**

22.1 Introduction

22.2 Short Cavity FP

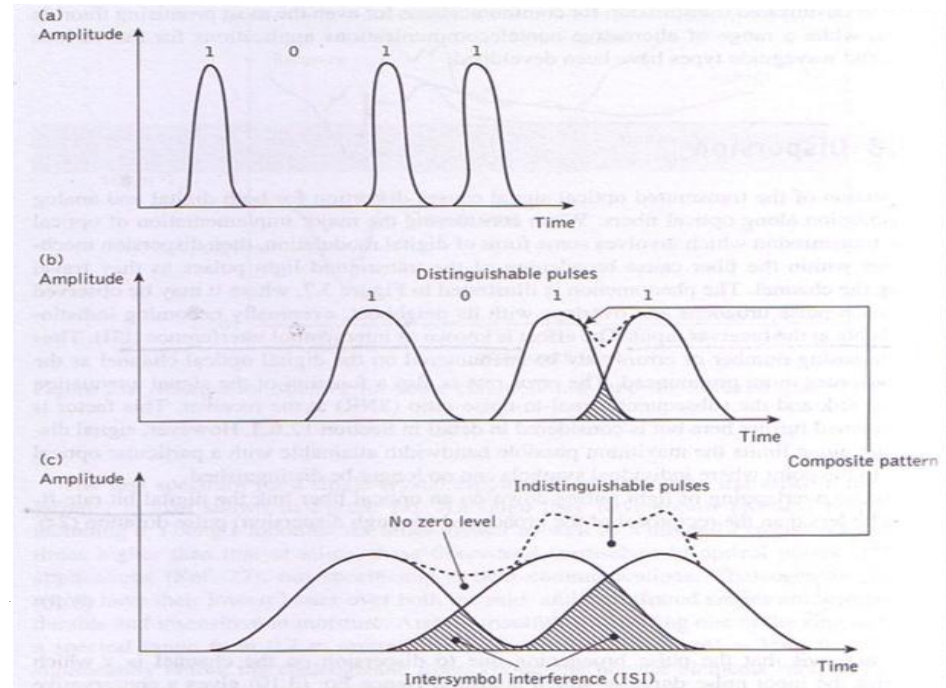
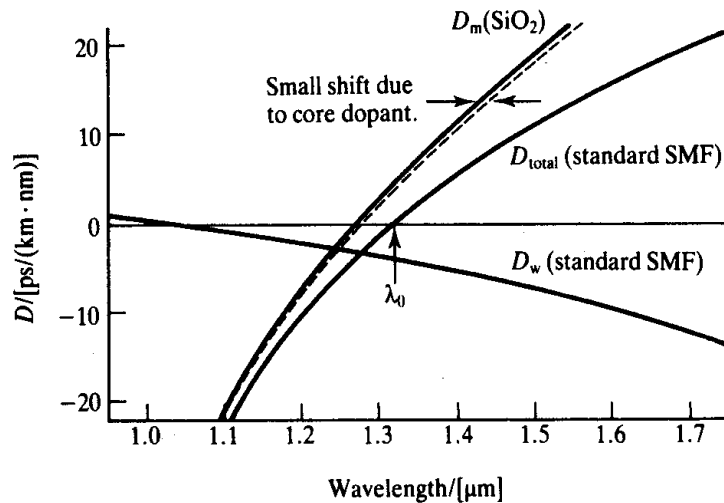
22.3 DBR

22.4 DFB

22.5 VCSEL

22.6 Wavelength Tuning

# Introduction (i)



• Previous slides:

1. Dispersion limits bit rate and long distance

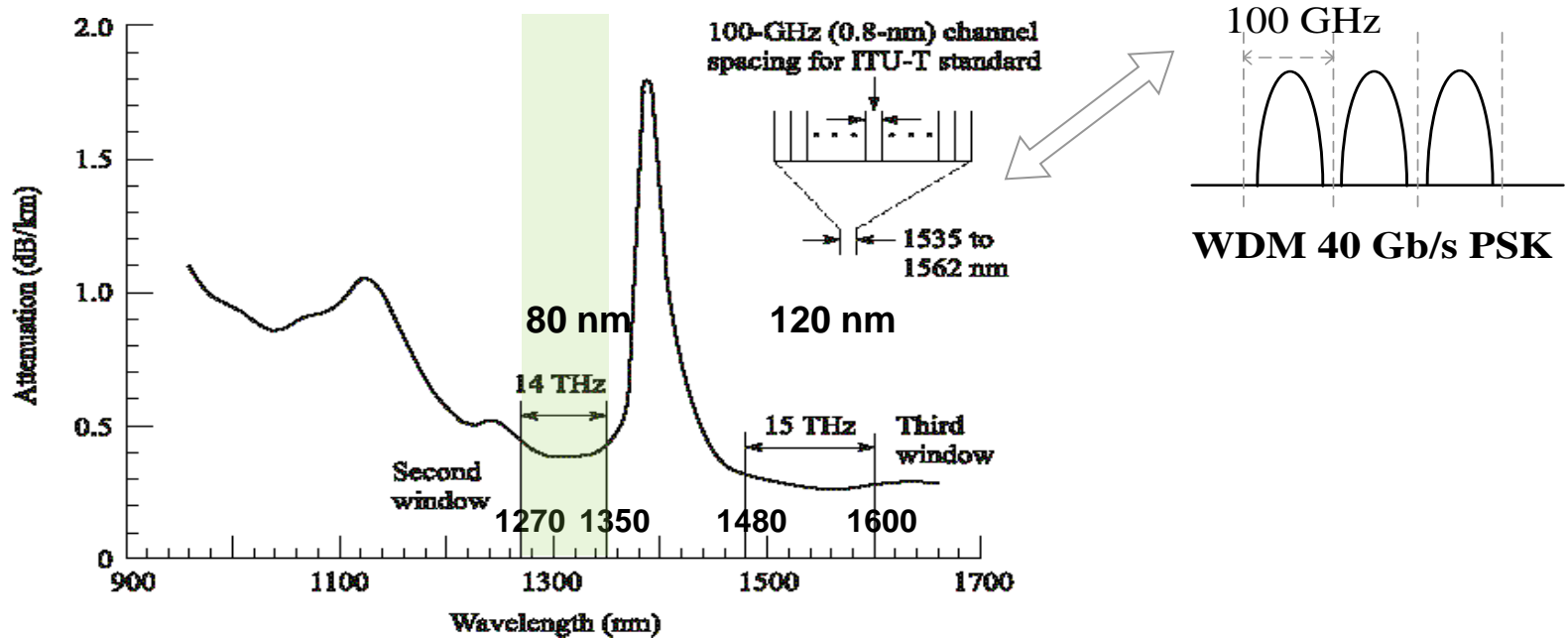
$$\Delta\delta t = L\Delta\lambda D$$

$$B \propto 1/(L\Delta\lambda D)$$

A maximum pulse broadening of **50% of the bit slot**:  $BL = 1/(2\Delta\lambda D)$

2. Transmission – need a narrow linewidth to minimise pulse broadening

# Introduction (ii)



- We also need a narrow linewidth emitter in order to maximise WDM capacity

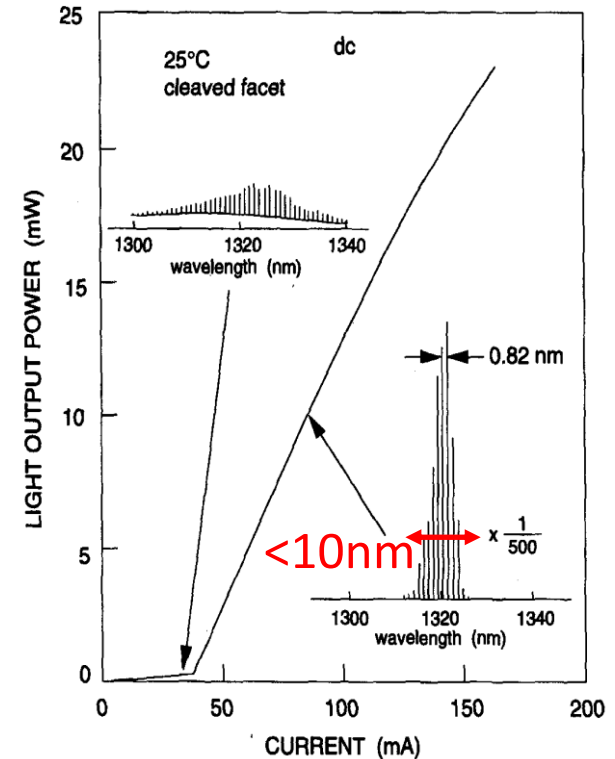
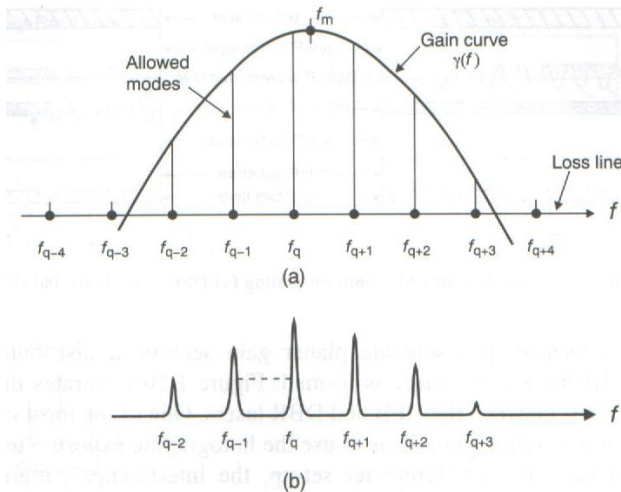
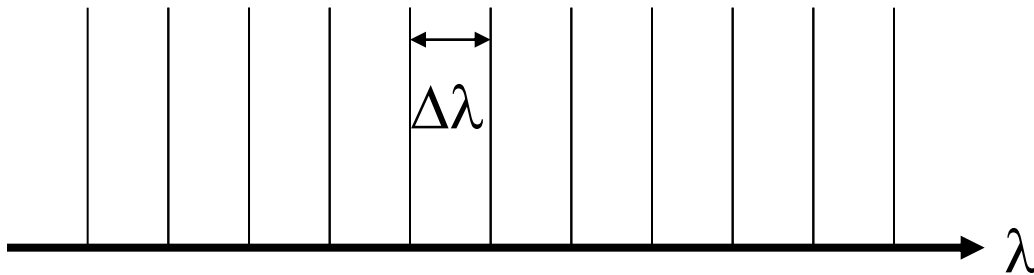
- **Optical Band width**

$$|\Delta \nu| = \left( \frac{c}{\lambda^2} \right) |\Delta \lambda|$$

Laser line width is 0.8 nm (**~100 GHz**), a single optical fibre can carry 50 pulses

- **Temperature stability**
- **Single mode**

# Single Mode Laser – widely spaced FP modes



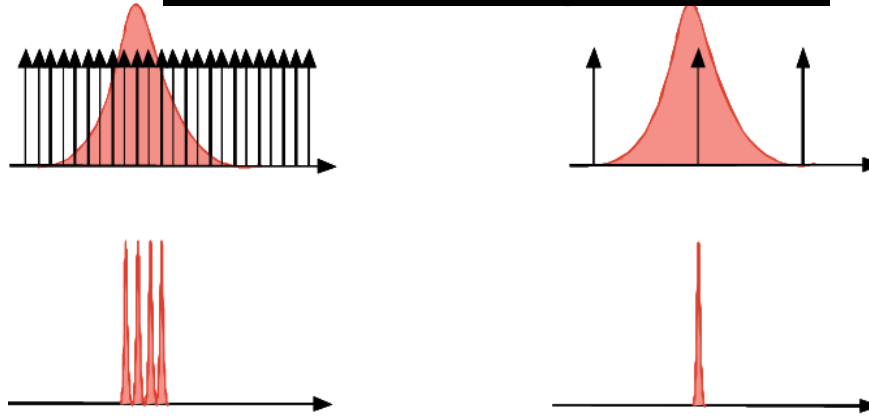
- Previous slides show:

$$m\lambda/2 = nL$$

$$\Delta\lambda = \lambda^2/2nL$$

- Make the spacing large enough so that only one lasing mode is allowed
- Requirements: **mode spacing  $\geq$  gain spectrum width**

# Short Cavity Lasers



- For example: refractive index  $\sim 3$ ,  $\lambda_0 = 1.55 \mu\text{m}$ , if  $\Delta\lambda$  required: **20nm**
- The cavity length:  $\Delta\lambda = \lambda^2 / 2nL$
- **So  $L = 20 \mu\text{m}$**

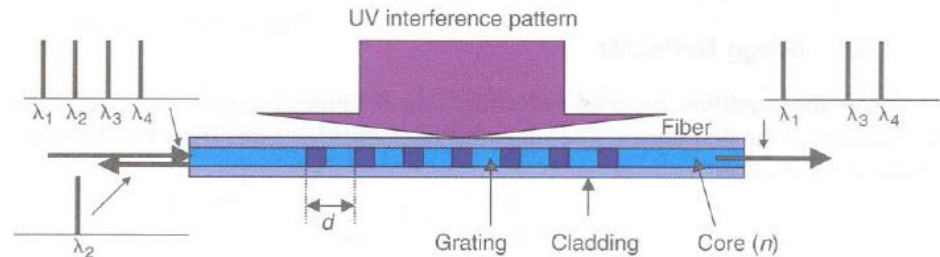
Problems to overcome –

$$g_{th} = \frac{1}{\Gamma} \left[ \alpha_i + \frac{1}{2L} \ln\left(\frac{1}{R_1 \cdot R_2}\right) \right]$$

- $L$  is so small that mirror **reflectivity** needs to increase, ensuring low losses
- High power: need large current through small volume – cooling problems?
- Cleavage: **extremely difficult** (Recently, laser cleaving)
  - try cleaving  $20 \mu\text{m}$  from a  $100 \mu\text{m}$  thick semiconductor....
  - analogous to braking  $5\text{mm}$  thick chocolate into  $1\text{mm}$  slices

# Bragg Gratings

- Previously we have known: **Fibre Bragg gratings** can be used as a wavelength selective filter



- The selective wavelength must meet the requirements in order to form constructive interference between the reflected beams

$$\lambda = 2 \cdot n_{eff} \cdot d$$

where  $n_{eff}$ : the average refractive index of the material; d: grating period.

- If d is fixed, **only  $\lambda$  meeting the above equation can be selected**

The idea can be used for the fabrication of a single wavelength laser

- Grating **in the gain region** (active region): **DFB laser**
- Grating **outside the gain region** (active region): **DBR laser**

# Distributed Bragg Reflector (DBR) Laser



- **Bragg condition:**  $\lambda_B = 2 n_{avg} d / m$ , where  $m=1,2,\dots$ , and **d: period**
- Only allowed wavelengths: **when the wavelength satisfies the Bragg condition to form constructive interference**

For example to design DBR/DFB structure (i.e., **d: period**)

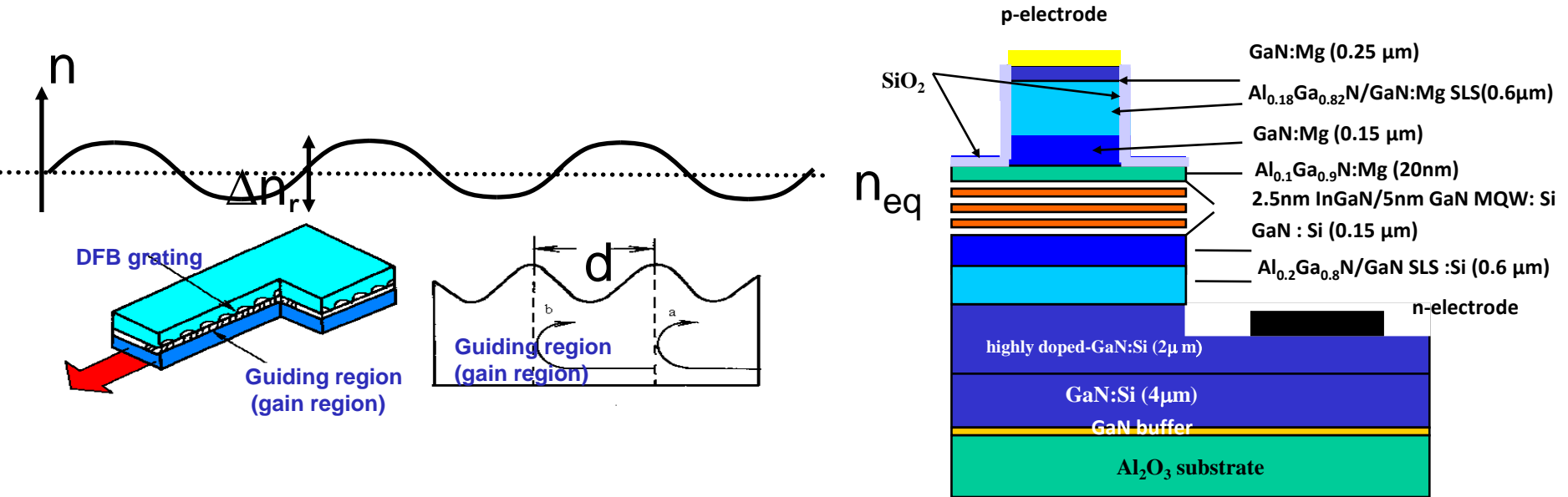
$$\lambda_{Bragg} = 2 n_{avg} d / m \quad \Rightarrow \quad d = m \lambda_{Bragg} / 2 n_{avg}$$

Choose the 1st order:  $m = 1$ ,  $\lambda_{Bragg} = 1.55 \mu m$ ,  $n_{eq} = 3$

Therefore, we can obtain:  $d \sim 250 nm$

- **The period required is on the nanometre scale** (think how to fabricate)

# Distributed Feedback Laser



- **Bragg condition:**  $\lambda_B = 2 n_{eq} d / m$ , where  $m = 1, 2, \dots$ , and **d: period**. Usually use  $m=1$ .  $m \neq 1$  not on gain peak.

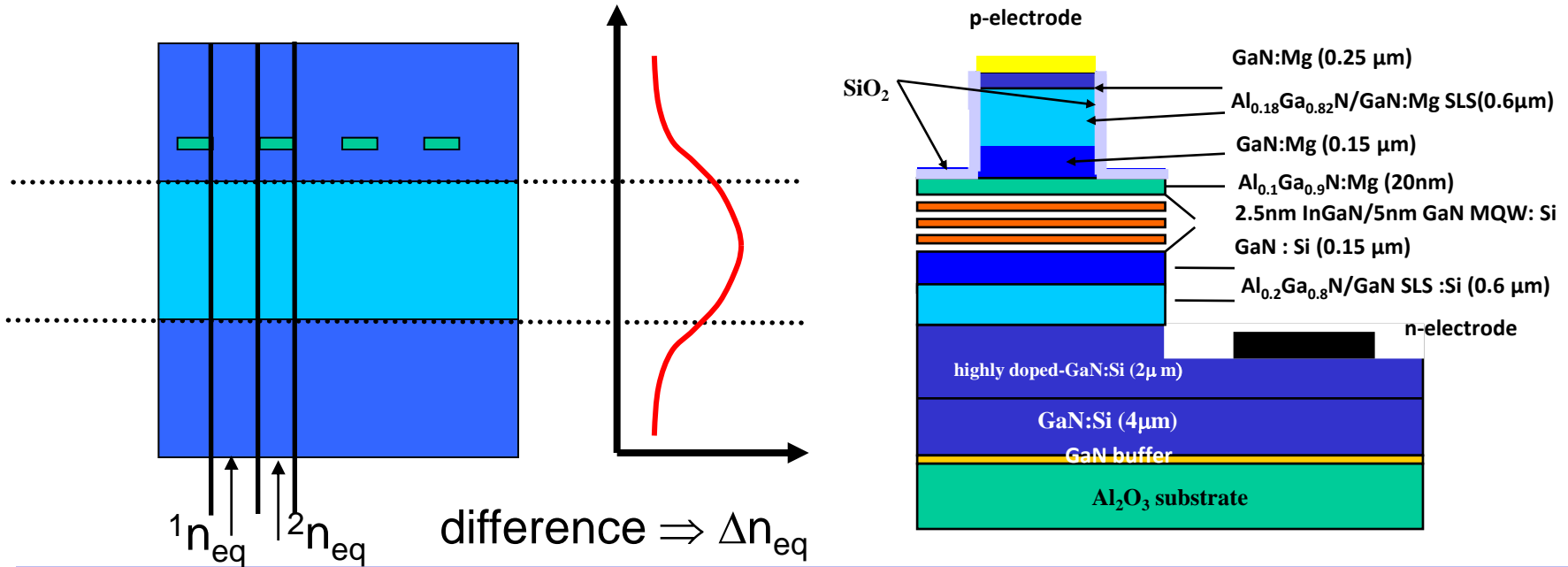
Basically, when the lasing  $\lambda$  is close to  $\lambda_B$ , such lasing wavelength is allowed

**In reality, it is not so simple. The special grating:**

- (1) It modifies the **refractive index** periodically
- (2) It also modifies the **gain in the active region** periodically



# Distributed Feedback Laser – Coupling Strength



- A detailed calculation is complicated, depending on **Coupling Strength**, i.e., the fraction of optical power reflected:

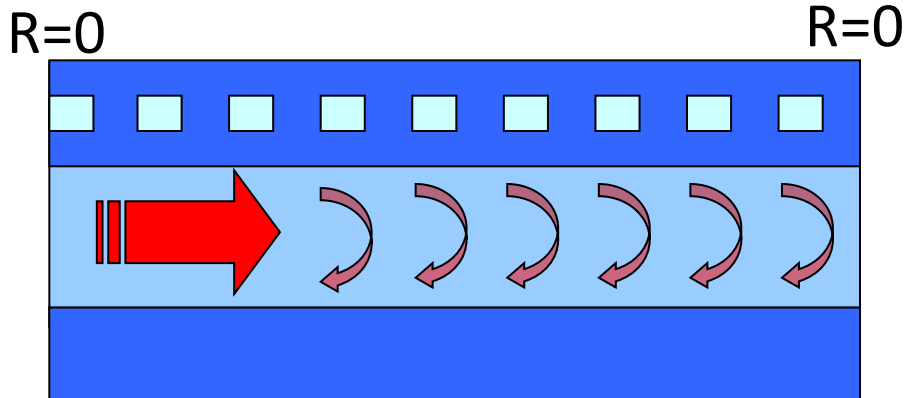
(1) Thickness of the waveguiding layer; (2) Depth of the grating pitch; (3) Length of the grating region

- **Introduction of a coupling constant** (based on perturbation assumption)

$$\kappa = \pi \Delta n_{eq} / \lambda_B$$

Increase  $\kappa$  by increasing index contrast – thicker grating layer, closer to optical mode, etc.

# DFB Modes – Emission Spectra

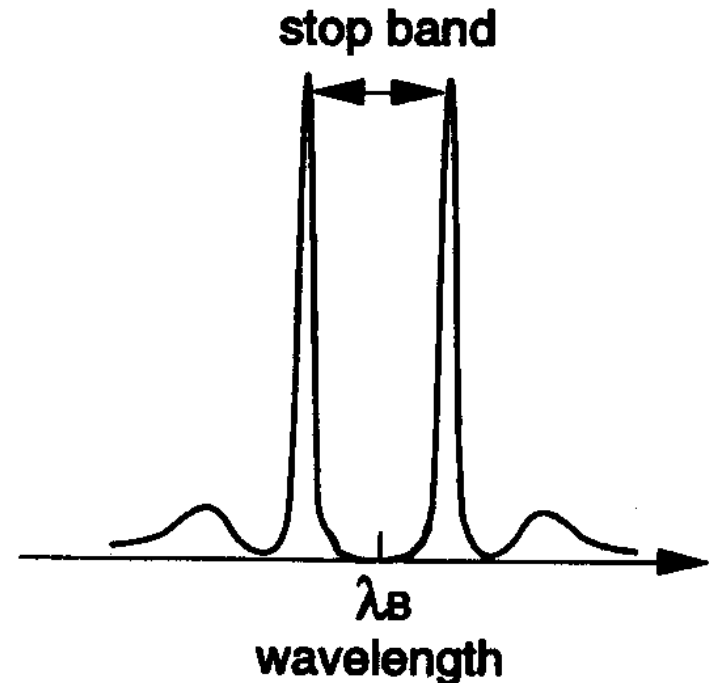


- In reality, the allowed wavelengths are close to  $\lambda_{\text{Bragg}}$ , but **not exactly  $\lambda_{\text{Bragg}}$**

- Lasing at two modes on either side of  $\lambda_{\text{Bragg}}$

$$\lambda = \lambda_{\text{Bragg}} \pm \frac{\left(m + \frac{1}{2}\right)}{2nL} \lambda_{\text{Bragg}}^2$$

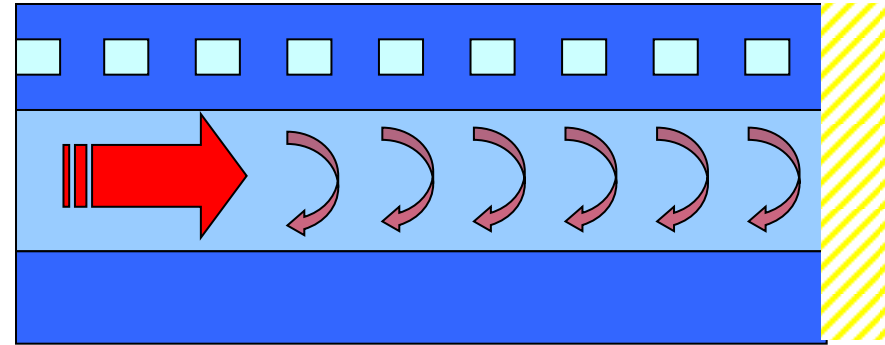
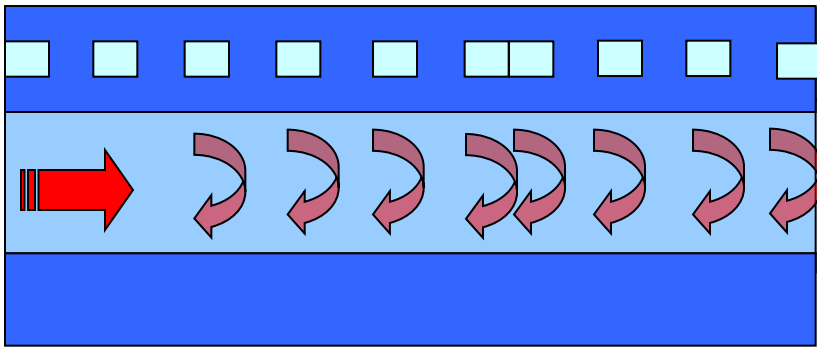
- Stop band width is function of  $\kappa$



uniform grating

It is still not **good enough** as two modes are allowed

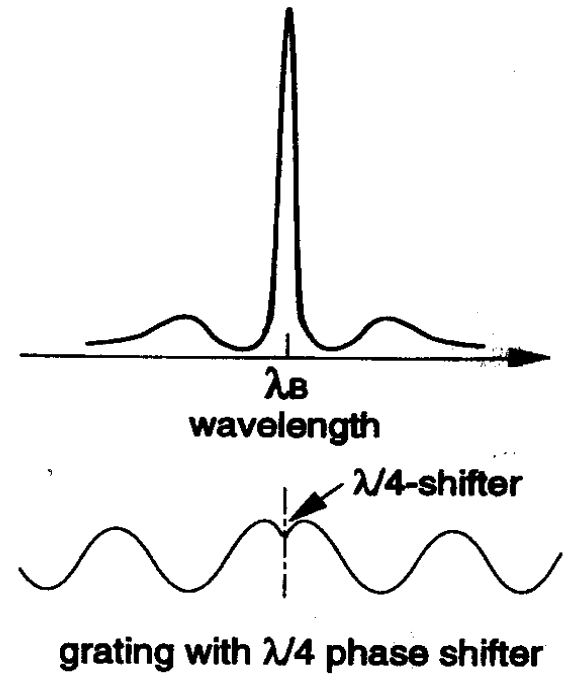
# Single mode DFB laser



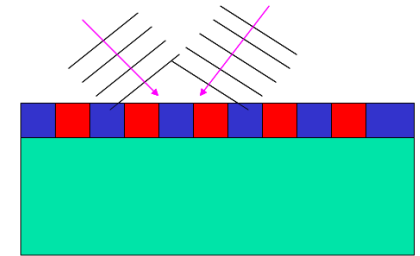
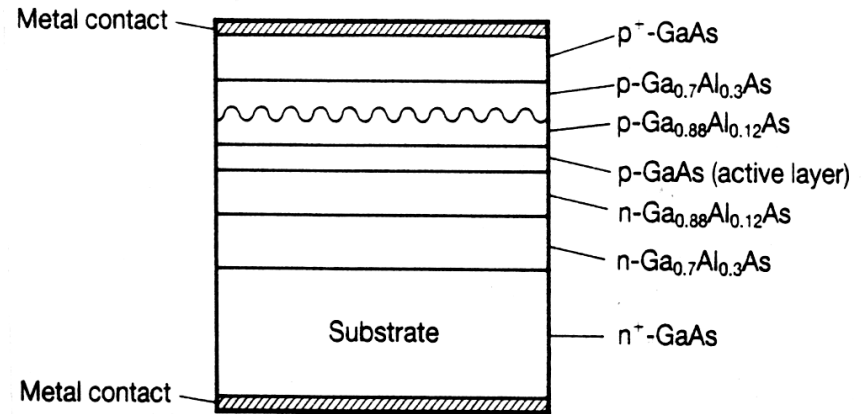
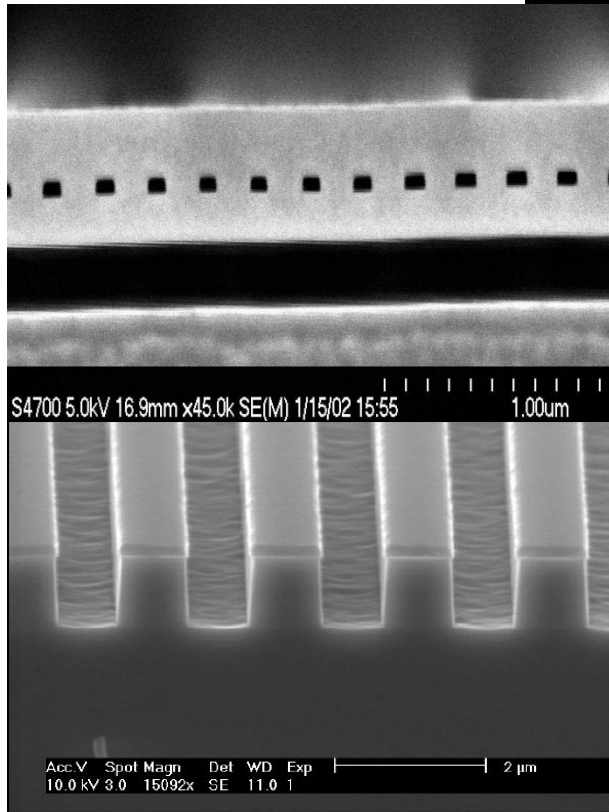
- Introducing additional  $\pi/2$  phase shift to get single mode operation (introduce “defect” or destroy “symmetry” in order to lift degeneracy)

1- Put phase shift in grating

2- Make one facet a high reflecting mirror



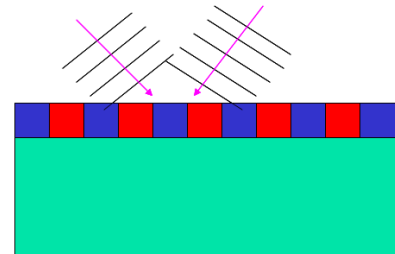
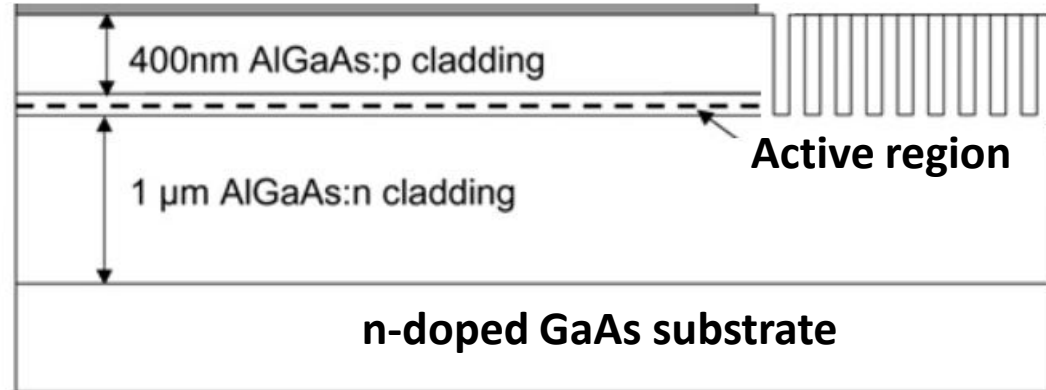
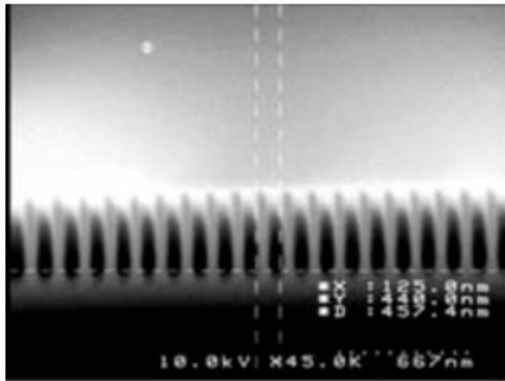
# DFB laser Fabrication (i)



## • Combination of epitaxial overgrowth and nanofabrication techniques

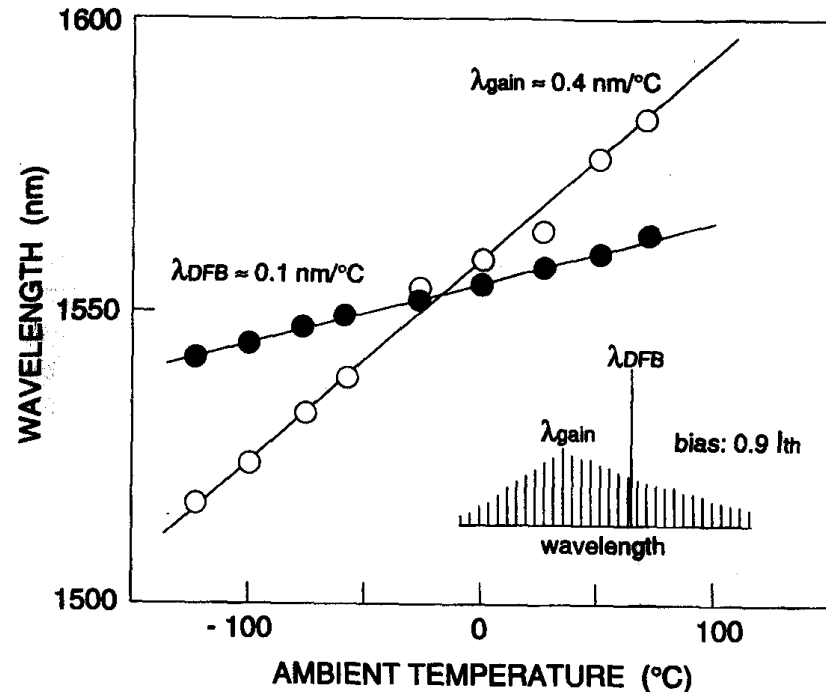
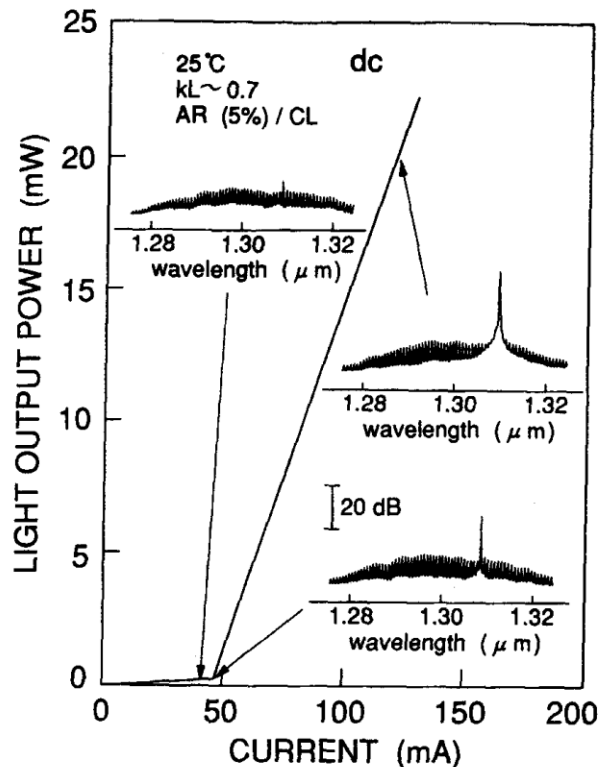
- (1) Partial epitaxial growth of laser structure (interrupted at guiding layer just above active region): **MBE or MOCVD**
- (2) Designing/patterning grating structure: **holography or e-beam lithography**
- (3) Fabricating grating structure: **dry-etching or wetting etching**
- (4) Completing epitaxial growth: **MBE or MOCVD**

# DBR laser Fabrication (ii)



- Easier than fabrication of DFB, and epitaxial overgrowth is unnecessary
- (1) Design/patterning grating structure: **holography or e-beam lithography**
  - (2) Fabricating grating structure: **dry-etching or wetting etching**

# DFB Performance



Compared with other laser diodes

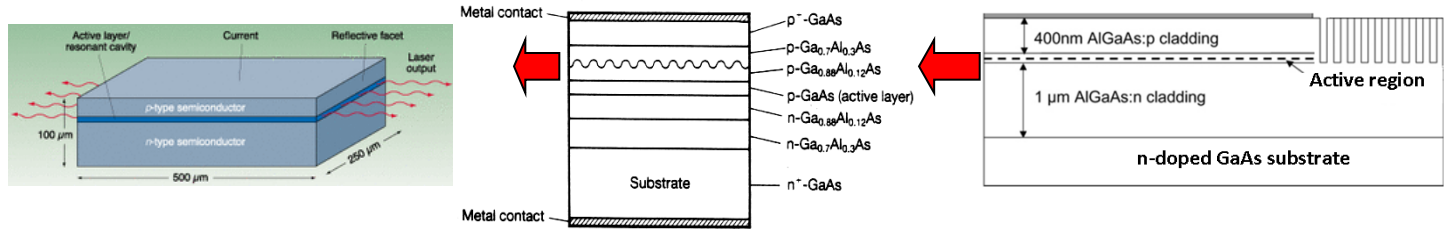
- **Extremely narrow** linewidth
- Wavelength set by grating – **less sensitive** to temperature

Both meet requirements for the DWDM application very well

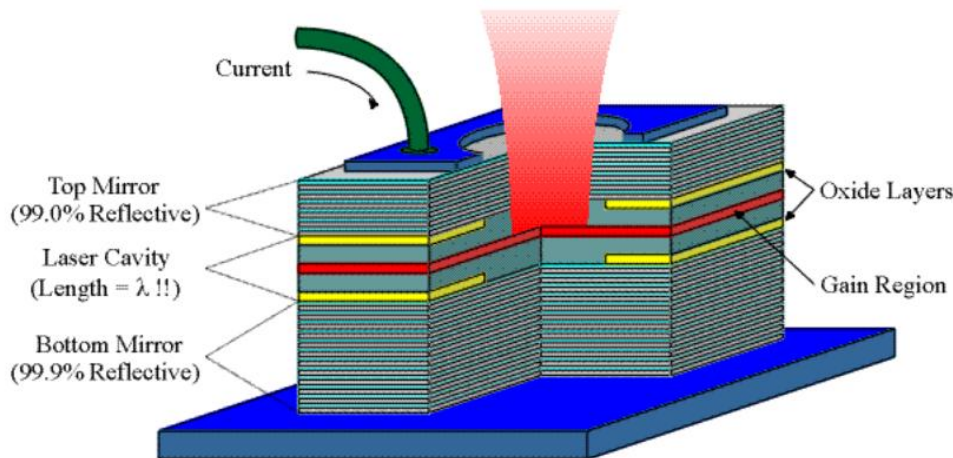
# Vertical Cavity Surface Emitting Laser (VCSELs) (i)

So far, we have known a number of laser diodes:

- (1) F-P laser
- (2) DBR laser
- (3) DFB laser

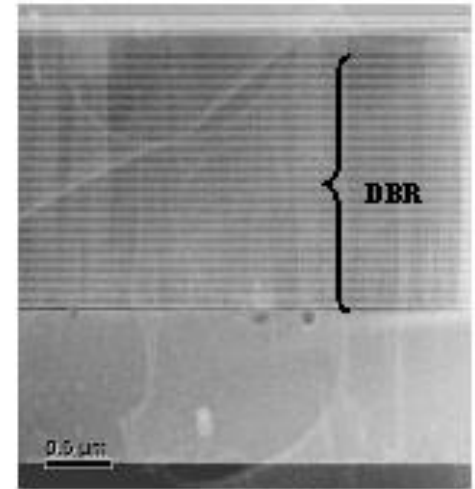
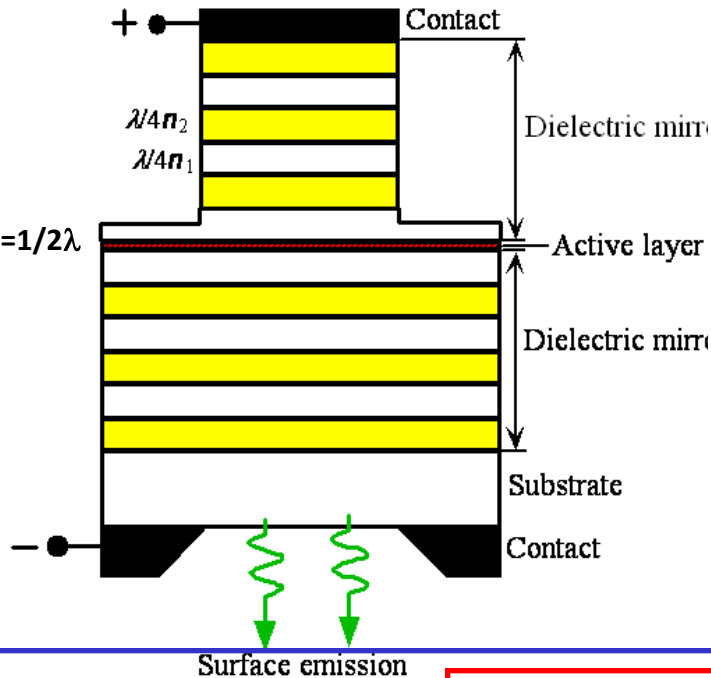
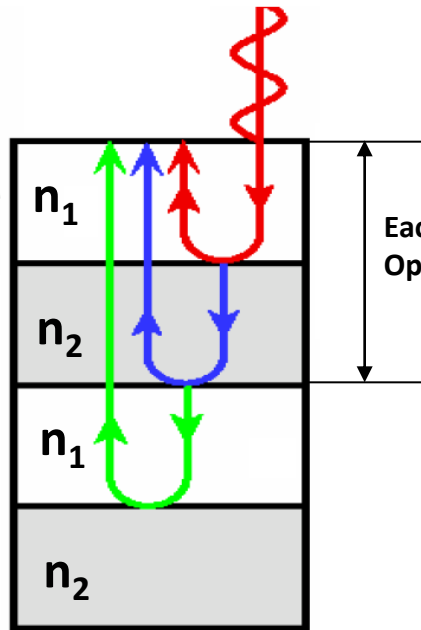


Basically, they are (1) under an **edging-emitting** configuration; and  
(2) based on an optical cavity on the **ten or hundred micrometre scale**



- **Surface emitting laser**
- Cavity length: **wavelength scale ( $\sim \lambda$ )**
- **DBR** on top and bottom (reflectivity  $\sim 100\%$ )

# Vertical Cavity Surface Emitting Laser (VCSELs) (ii)



Sheffield nitride DBR

- Both bottom and top DBRs require:

(1) ~100% reflectivity;

$$R = \left[ \frac{(n_{h1}/n_{L2})^{2N} - 1}{(n_{h1}/n_{L2})^{2N} + 1} \right]^2$$

(2) Many pairs required: each pair consisting of **two layers** with an optical thickness  $1/2\lambda$ , i.e.,  **$1/2 \lambda = n_1 d_1 + n_2 d_2$**

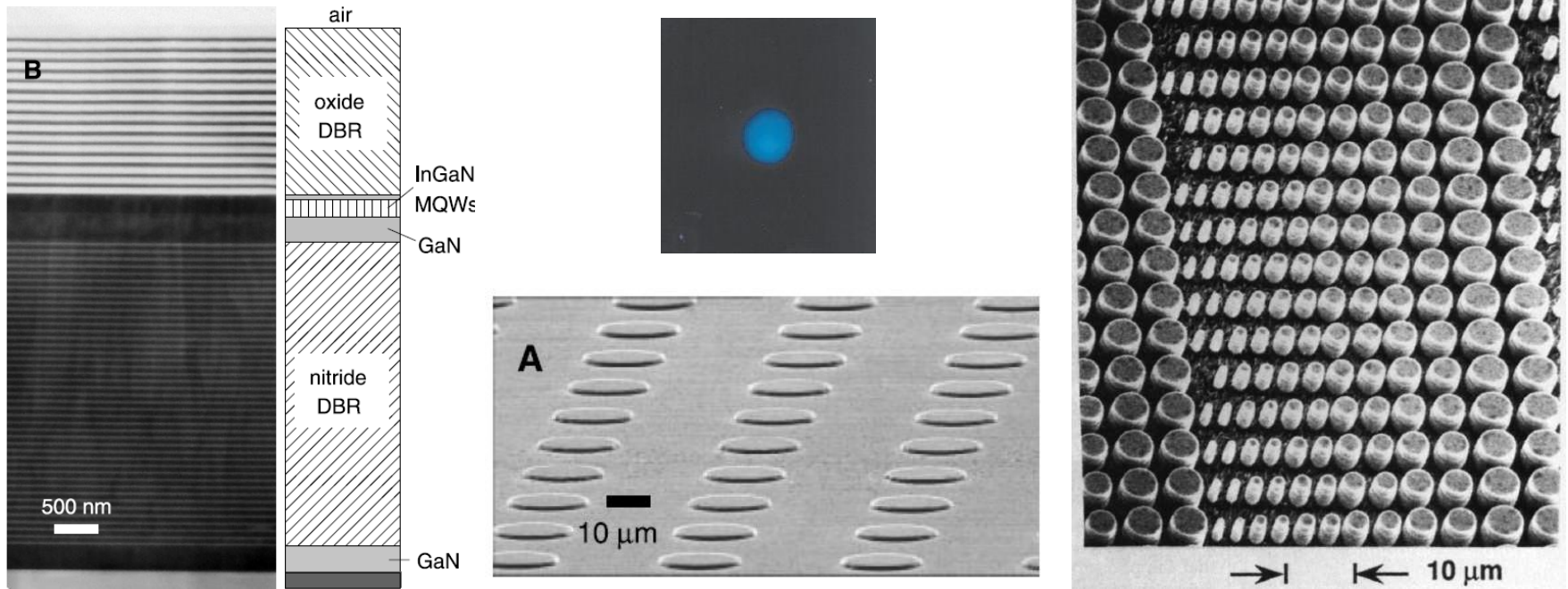
where  $n_1$  and  $n_2$ : refractive indices; and  $d_1$  and  $d_2$ : thickness for each layer

(3) Optical cavity (L):  **$m (n\lambda)$** , where  $m$ : integer,  $n$ : refractive index

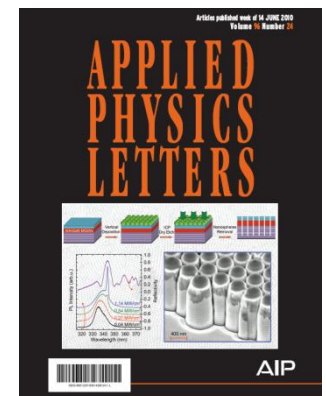
- For example:  $d_1$  and  $d_2$ : ~120 -130 nm (if  $\lambda=1.55\mu\text{m}$ ,  $n_1$  and  $n_2$ :~3.2/3.0)

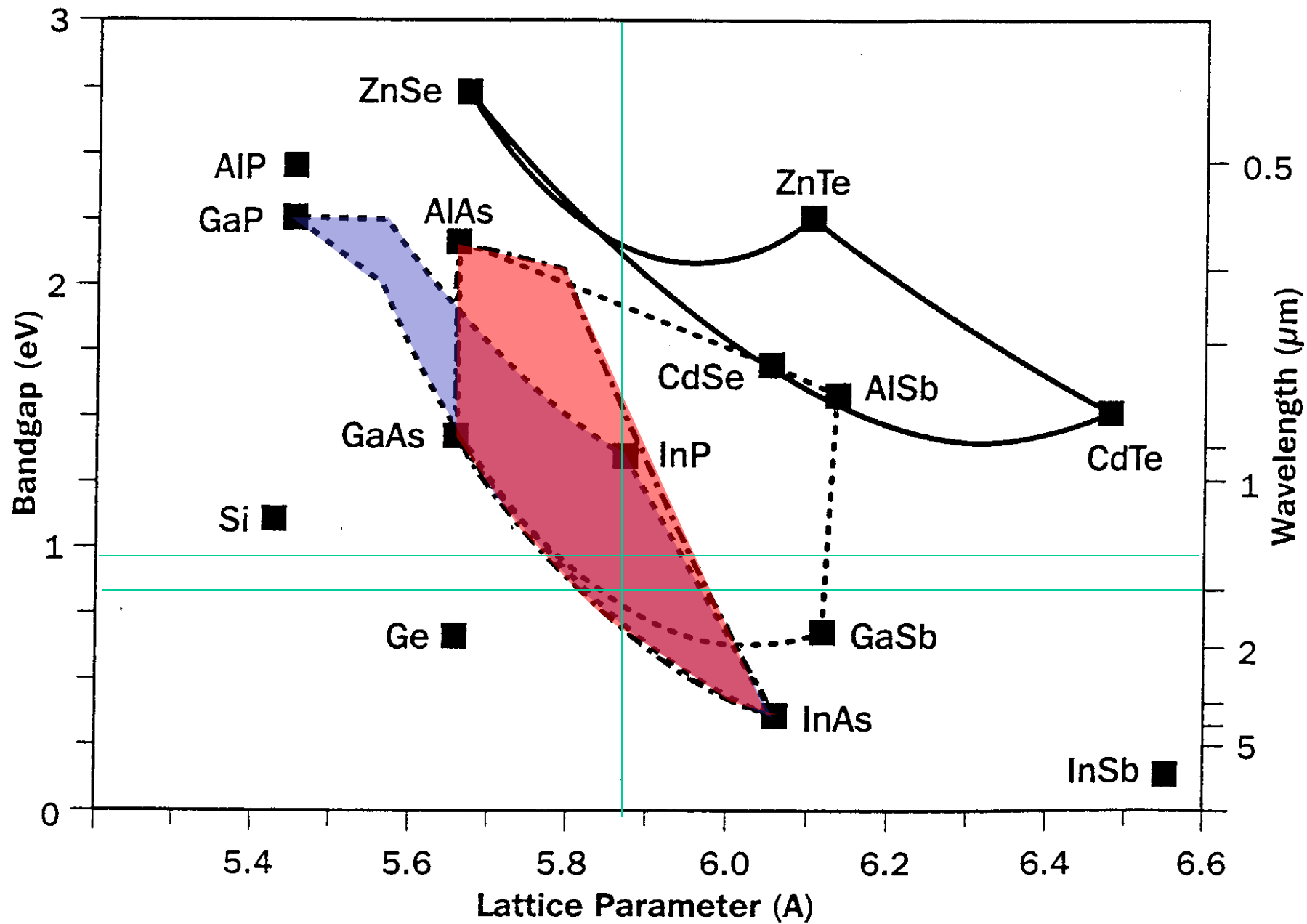


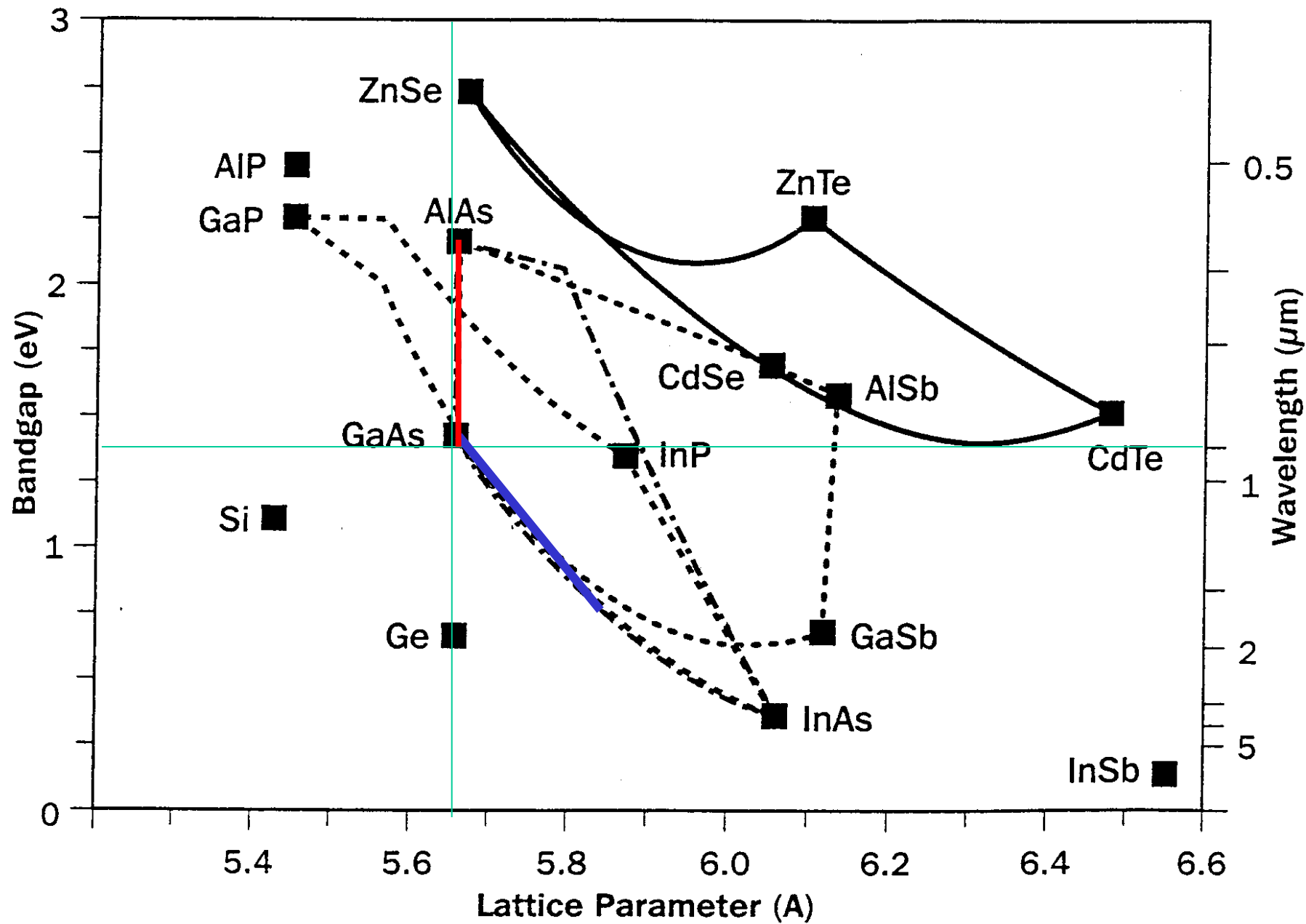
# Fabrication of VCSELs



- Ease fabrication in a **two dimensional array**
- Laser beam shape: best due to a circularly symmetric confinement, thus offering excellent coupling with optical fibre
- Challenge: material growth due to the requirement of many pairs of DBR
- Sheffield team has achieved the shortest wavelength VCSELs







# Materials and Applications

- 1.3 $\mu$ m – 1.65  $\mu$ m

- InP based materials, AlInGaAs, GaInAsP alloys

- ~MANs ~ 1300nm systems

- (~10GBit/s ~10km 1300nm DFB)

- (~1 Gbit/s ~few km 1310nm FP)

- ~WANs ~1550nm systems

- (~10GBit/s ~40km 1550nm DFB)

- 850nm

- GaAs based materials (AlGaAs, InGaAs alloys)

- ~LANs – e.g. 10GBit/s over ~300m

- 980nm-EDFA Pump laser

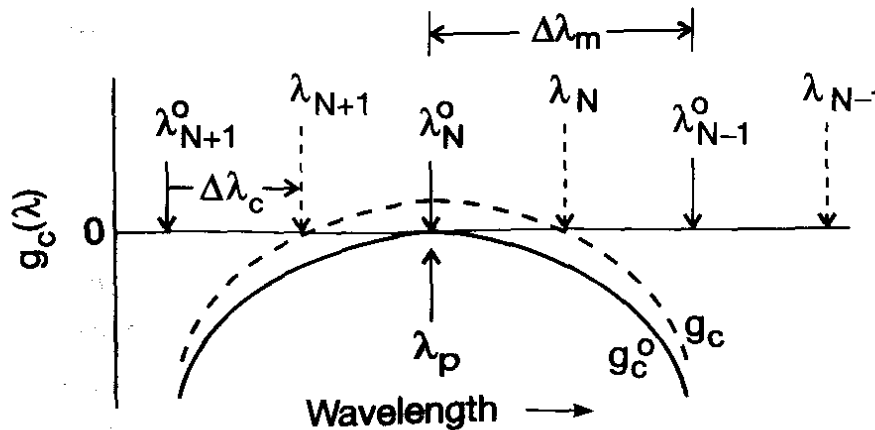
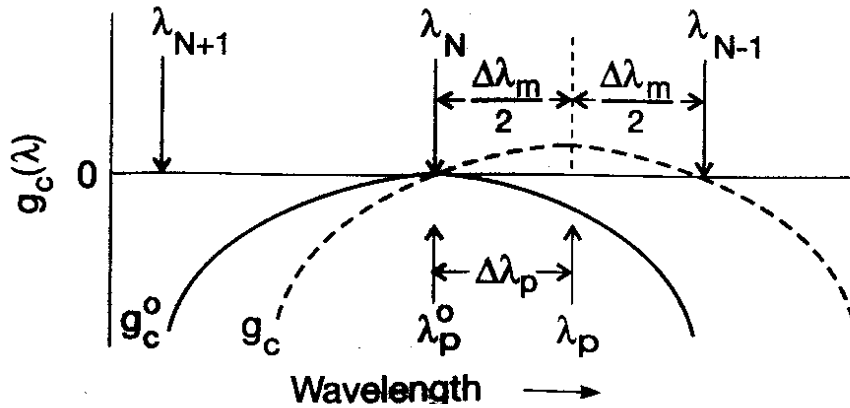
- GaAs based materials (AlGaAs/InGaAs)

# Wavelength Tuneable Lasers

For DWDM it is desirable to have wavelength tuneable lasers

- Need to compensate for the ageing of laser wavelength shift with age
- Need to reduce component inventory both manufacturer and in field
- Also many applications in gas sensing, spectroscopy, etc.

# Tuning Methods



## 1) Alter cavity gain spectrum

– short cavity laser  
with thermal or free carrier tuning of  
gain spectrum peak wavelength

- Increased current changes  $\lambda_{\text{Bragg}}$  for mirrors – thermal and free carrier effects
- Thermal tuning allows gain spectrum change

## 2) Alter allowed modes

Extra cavity

## 3. Alter allowed modes and gain 22

## **Summary Topic 22**

- Narrow linewidth of laser emission is desirable (DWDM, dispersion)
- A number of possibilities exist – short cavity F-P, DFB, DBR, VCSEL, all with their relative advantages and disadvantages
- Tuneable wavelength is also desirable ...DWDM
- Various possibilities exist – tune gain spectrum, lasing modes, or both

# Tutorial Questions

T22.1 Describe the possible optical modes of a laser diode and how they may be controlled to obtain a single mode laser.

T22.2 Review the different methods to obtain a single longitudinal mode laser.

T22.3 Why is a tuneable single-mode laser desirable? How may this be achieved?

T22.4

- (a) A laser diode has length  $100\text{ }\mu\text{m}$ , operates at  $1300\text{nm}$ , has effective refractive index of 3.5. What is the F-P mode spacing?
- (b) For this laser both facets have a reflectivity of 0.5. Assuming no internal loss, calculate the threshold gain of the laser.